

Ultra Low Capacitance Two-line
Bidirectional TVS Diode

# **General Description**

The AOZ8832 is an ultra low capacitance one-line bidirectional transient voltage suppressor diode designed to protect high speed data lines and voltage sensitive electronics from high transient conditions and ESD.

This device incorporates one bidirectional TVS diode in an ultra-small 0201 footprint package. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15 kV air, ±15 kV contact discharge).

The AOZ8832 comes in an RoHS compliant package and is rated over a -40 °C to +85 °C ambient temperature range.

The ultra-small 1.0mm x 0.6 mm x 0.5 mm DFN package makes the AOZ8832 ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

#### **Features**

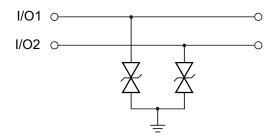
- ESD protection for high-speed data lines:
  - Exceeds: IEC 61000-4-2 (ESD) ±12 kV (air), ±12 kV (contact)
  - Human Body Model (HBM) ±15 kV
- Ultra low capacitance: 0.4 pF
- Low clamping voltage
- Low operating voltage: 5.0 V
- Pb-free device

# **Applications**

- Portable handheld devices
- Keypads, data lines, buttons
- Notebook computers
- Digital Cameras
- Portable GPS
- MP3 players

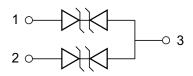


# **Typical Application**



**Bidirection Protection of Two Lines** 

# **Pin Configuration**





# **Ordering Information**

Part Number	Part Number Ambient Temperature Range		Environmental
AOZ8832DI-05	-40 °C to +85 °C	DFN 1.0 x 0.6	Green Product RoHS Compliant



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

# **Absolute Maximum Ratings**

Exceeding the Absolute Maximum Ratings may damage the device.

Parameter	Rating
VP – VN	5 V
Peak Pulse Current ( $I_{PP}$ ), $t_P = 8/20\mu s$ (IEC61000-4-5)	2 A
Peak Pulse Power, t <sub>P</sub> = 8/20μs	30 W
Storage Temperature (T <sub>S</sub> )	-65 °C to +150 °C
ESD Rating per IEC61000-4-2, Contact <sup>(1)</sup>	±12 kV
ESD Rating per IEC61000-4-2, Air <sup>(1)</sup>	±12 kV
ESD Rating per Human Body Model <sup>(2)</sup>	±15 kV

- 1. IEC 61000-4-2 discharge with  $C_{Discharge}$  = 150 pF,  $R_{Discharge}$  = 330  $\Omega$ . 2. Human Body Discharge per MIL-STD-883, Method 3015  $C_{Discharge}$  = 100 pF,  $R_{Discharge}$  = 1.5 k $\Omega$ .

# **Maximum Operating Conditions**

The device is not guaranteed to operate beyond the Maximum Operating Conditions.

Parameter	Rating
Junction Temperature (T <sub>J</sub> )	-40 °C to +125 °C

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# **Electrical Characteristics**

 $T_A = 25$ °C unless otherwise specified. Specifications in **BOLD** indicate a temperature range of -40 °C to +85 °C.

Symbol	Parameter	Diagram
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current	!
V <sub>CL</sub>	Clamping Voltage @ I <sub>PP</sub>	IPP
$V_{RWM}$	Working Peak Reverse Voltage	
I <sub>R</sub>	Maximum Reverse Leakage Current	V <sub>CL</sub> V <sub>BR</sub> V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage	IT VRWM VBR VCL
P <sub>PK</sub>	Peak Power Dissipation	
СЛ	Capacitance @ V <sub>R</sub> = 0 and f = 1 MHz	lpp

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>RWM</sub>	Reverse Working Voltage <sup>(3)</sup>	Between pins 1 and 2			5.0	V
V <sub>BR</sub>	Reverse Breakdown Voltage <sup>(4)</sup>	I <sub>T</sub> = 1 mA, between pins 1 and 2	6.0	9.4	10.0	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 5 V, between pins 1 and 2		0.05	0.1	μΑ
	Channel Clamp Voltage	$I_{PP} = 1 \text{ A}$ , $t_P = 100 \text{ ns}$ , between pins 1 and 2		11.5	14.0	V
		$I_{PP} = 2 \text{ A}$ , $t_P = 100 \text{ ns}$ , between pins 1 and 2		13.0	16.0	V
		$I_{PP} = 5 \text{ A}$ , $t_P = 100 \text{ ns}$ , between pins 1 and 2		16.3	19.5	V
V <sub>CL</sub>		I <sub>PP</sub> = 1 A, IEC61000-4-5, 8/20 μs, between pins 1 and 2		12.8	15.5	V
		I <sub>PP</sub> = 2 A, IEC61000-4-5, 8/20 μs, between pins 1 and 2		15.3	20.0	V
СЈ	Junction Capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}, \text{ between pins 1 and 2}$		0.4	0.6	pF

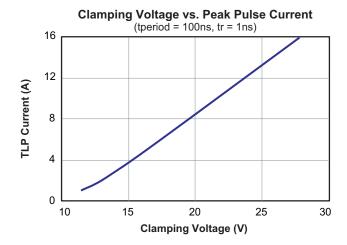
### Notes:

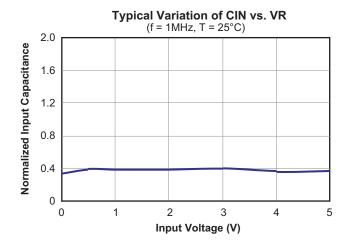
 $<sup>3. \</sup> The \ working \ peak \ reverse \ voltage \ (V_{RWM}) \ should \ be \ equal \ to \ or \ greater \ than \ the \ DC \ or \ continuous \ peak \ operating \ voltage \ level.$ 

<sup>4.</sup>  $V_{BR}$  is measured at the pulse test current  $I_{T}$ .



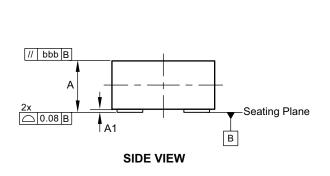
# **Typical Performance Characteristics**

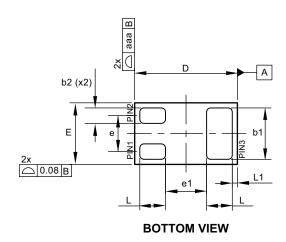




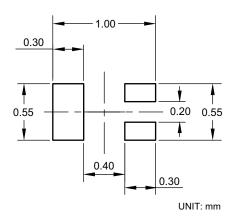


# Package Dimensions, DFN 1.0x0.6\_3L





### **RECOMMENDED LAND PATTERN**



## **Dimensions in millimeters**

Symbols	Min.	Nom.	Max.	
Α	0.50	0.52	0.55	
A1	0.00	0.03	0.05	
b1	0.45	0.50	0.55	
b2	0.10	0.15	0.20	
D	0.95	1.00	1.075	
E	0.55	0.60	0.675	
е		0.35		
e1		0.40		
L	0.20	0.25	0.30	
L1				
aaa		0.15		
bbb				

## **Dimensions in inches**

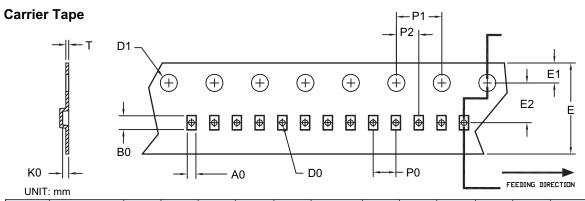
Symbols	Min.	Nom.	Max.		
Α	0.019	0.020	0.022		
A1	0.000	0.001	0.002		
b	0.018	0.020	0.022		
b2	0.004	0.006	0.008		
D	0.037	0.039	0.042		
E	0.022	0.024	0.027		
е		0.014			
e1		0.016			
L	0.008	0.010	0.012		
L1		0.002			
aaa		0.006			
bbb		0.002			

### Notes:

- 1. All dimensions are in milliteters. Angles are in degrees.
- 2. Coplanarity applies to the exposed heat sink slug as well as the terminals.

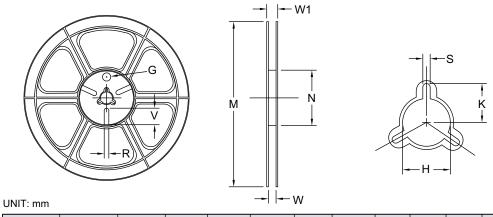


# Tape and Reel Dimensions, DFN 1.0x0.6



Option	Package	A0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
А	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.69 ±0.05	1.19 ±0.05	0.66 ±0.05	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.05	4.00 ±0.10	2.00 ±0.05	0.23 ±0.02
В	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.65 ±0.04	1.05 ±0.04	0.61 ±0.04	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.20 ±0.05

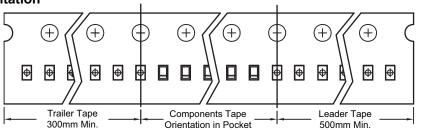




Tape Size	Reel Size	M	N	W	W1	Н	K	S	G	R	V
8mm	ø178	ø178	ø55	8.4	Max.	ø13.0	Max.	2.0	N/A	N/A	N/A
		±0.5	±1	+1.5/-0	14.4	±0.5	10.1	±0.5			

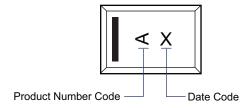
## **Leader/Trailer & Orientation**







# **Part Marking**



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